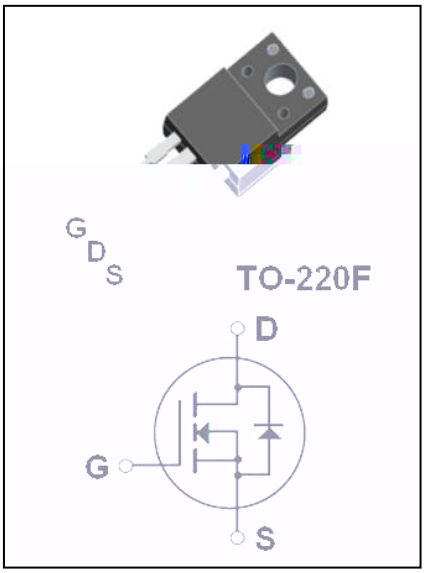
● **Features：**

- 7.0A, 650V, $R_{DS(on)(Typ)}$ =1.2Ω@V_{GS}=10V
- Low Gate Charge
- Low C_{rss}
- 100% Avalan he Tested
- Fast Swit hing
- Improved dv/dt Capa ility

● **Application:**

- High Frequen y Swit hing Mode Power Supply
- A tive Power Fa tor Corre tion



Absolute Maximum Ratings(T =25°C unless otherwise noted)

Sym ol	Parameter	Value	Unit
V_{DSS}	Drain-Sour e Voltage	650	V
I_D	Drain Current - Continuous(T =25°C)	7.0*	A
	- Continuous(T =100°C)	4.5*	A
I_{DM}	Drain Current -Pulsed (Note1)	28*	A
V_{GSS}	Gate-Sour e Voltage	±30	V
E_{AS}	Single Pulsed Avalan he Energy (Note2)	590	mJ
I_{AR}	Avalan he Current (Note1)	7.0	A
E_{AR}	Repetitive Avalan he Energy (Note1)	14.0	mJ
dv/dt	Peak Diode Re overy dv/dt (Note3)	4.5	V/ns
P_D	Power Dissipation(T_C =25°C)	48	W
	-Derate a ove 25°C	0.38	W/°C
Tj	Operating Jun tion Temperature	150	°C
Tstg	Storage Temperature Range	-55 to+150	°C

***** Drain Current Limited y Maximum Jun tion Temperature.

Thermal Characteristics

Sym ol	Parameter	Max	Unit
$R_{\theta JC}$	Thermal Resistan e,Jun tion to Case	2.6	°C /W
$R_{\theta JA}$	Thermal Resistan e,Jun tion to Am ient	62.5	°C /W

Electrical Characteristics(T =25°C unless otherwise noted)

Sym ol	Parameter	Test Conditons	Min	Typ	Max	Unit
Off Characteristics						
BV_{DSS}	Drain-sour e Breakdown Voltage	V_{GS}=0V ,I_D=250μA	650	--	--	V
$\triangle BV_{DSS}$ /$\triangle T_J$	Breakdown Voltage Temperature Coeffi ient	I_D=250μA (Referen ed to 25°C)	--	0.7	--	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS}=650V,V_{GS}=0V	--	--	1	μA
		V_{DS}=520V,T =125°C	--	--	10	μA
I_{GSSF}	Gate-Body Leakage Current,Forward	V_{GS}=+30V, V_{DS}=0V	--	--	100	nA
I_{GSSR}	Gate-Body Leakage Current,Reverse	V_{GS}=-30V, V_{DS}=0V	--	--	-100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}= V_{GS}, I_D=250μA	2.0	--	4.0	V
$R_{DS(on)}$	Stati Drain-Sour e On-Resistan e	V_{GS}=10 V, I_D=3.5A	--	1.2	1.4	Ω
g_{FS}	Forward Trans ondu tan e	V_{DS}=40 V, I_D=3.5A (Note4)	--	6.5	--	S
Dynamic Characteristics						
C_{iss}	Input Capa itan e	V_{DS}=25V,V_{GS}=0V, f=1.0MHz	--	1380	--	pF
C_{oss}	Output Capa itan e		--	170	--	pF
C_{rss}	Reverse Transfer Capa itan e		--	15	--	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 325 V, I_D = 7.0 A, R_G = 25 Ω (Note4,5)	--	13	--	ns
t_r	Turn-On Rise Time		--	100	--	ns
$t_{d(off)}$	Turn-Off Delay Time		--	126	--	ns
t_f	Turn-Off Fall Time		--	48	--	ns
Q_g	Total Gate Charge	V_{DS} = 520 V, I_D =7.0 A, V_{GS} = 10 V (Note4,5)	--	30	--	nC
Q_{gs}	Gate-Sour e Charge		--	6	--	nC
Q_{gd}	Gate-Drain Charge		--	14	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain-Sour e Diode Forward Current		--	--	7.0	A
I_{SM}	Maximum Pulsed Drain-Sour e Diode Forward Current		--	--	28	A
V_{SD}	Drain-Sour e Diode Forward Voltage	V_{GS} =0V,I_S=7.0A	--	--	1.4	V
t_{rr}	Reverse Re overy Time	V_{GS} =0V, I_S=7.0A, d I_F /dt=100A/μs (Note4)	--	315	--	ns
Q_{rr}	Reverse Re overy Charge		--	2.6	--	μC

Notes:

1、Repetitive Rating:Pulse Width Limited y Maximum Jun tion Temperature.

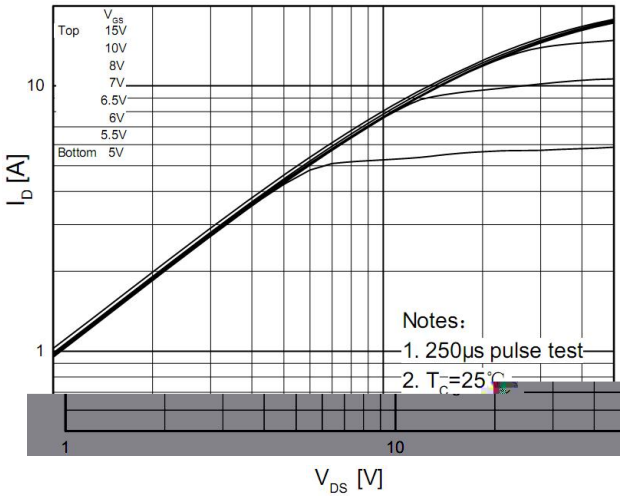
2、L = 19.5mH, I_{AS} =7.0A, V_{DD} = 50V, R_G = 25 Ω, Starting T_J = 25°C.

3、I_{SD}≤7.0A, di/dt≤200A/μs, V_{DD}≤BV_{DSS}, Starting T_J = 25°C.

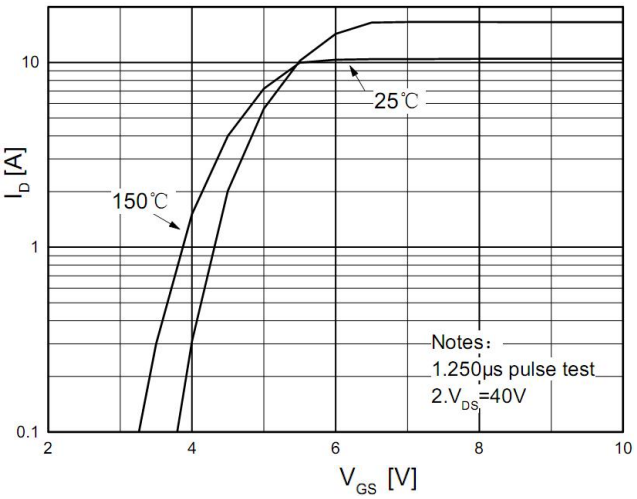
4、Pulse Test : Pulse Width ≤300 μ s, Duty Cy le≤2%.

5、Essentially Independent of Operating Temperature.

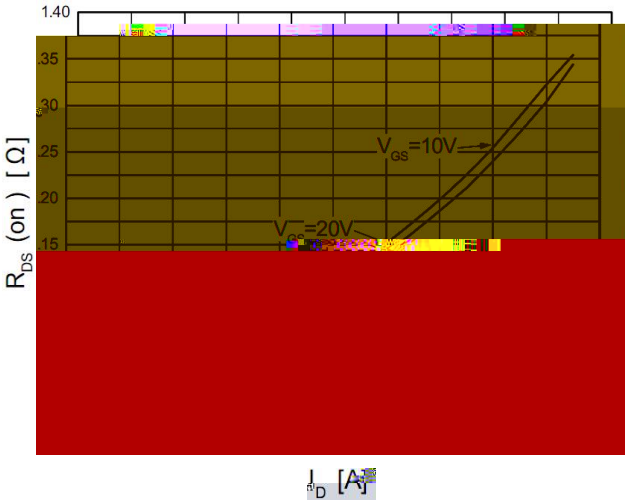
On-Regin Characteristics



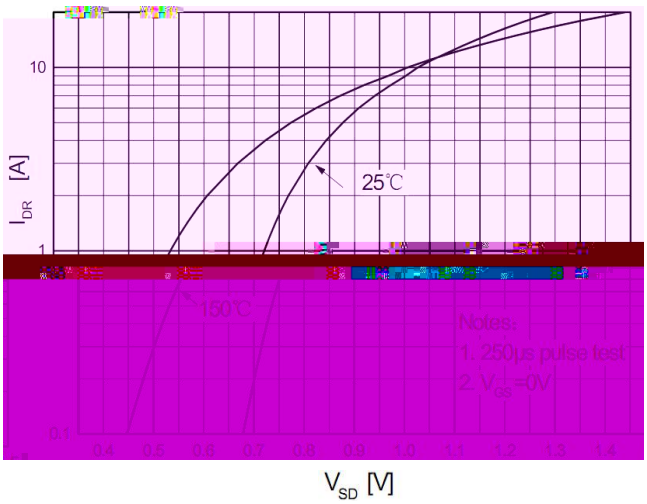
Transfer Characteristics



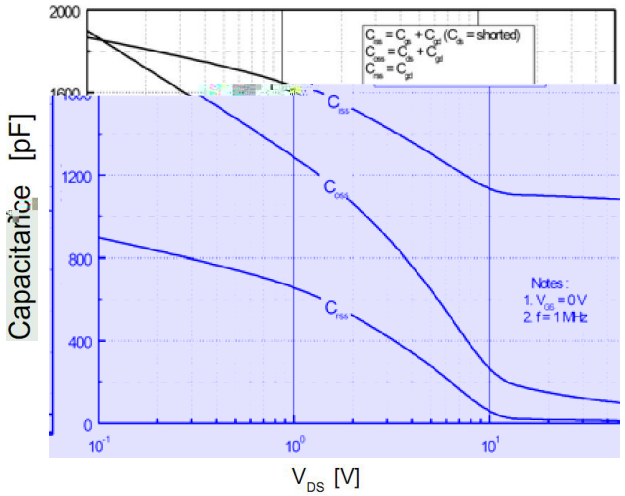
On-Resistance Variation vs. Drain Current and Gate Voltage



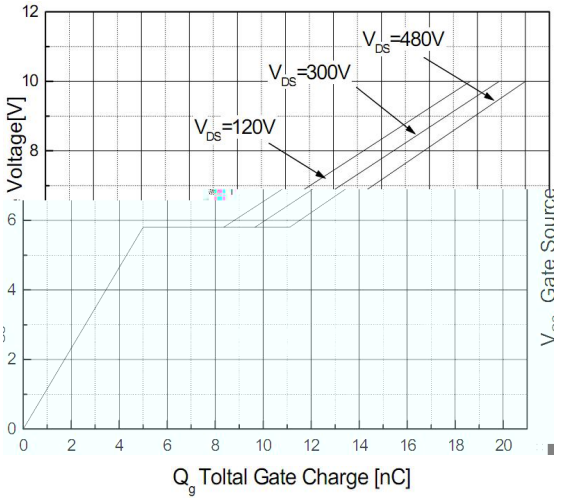
Body Diode Forward Voltage Variation vs. Source Current and Temperature



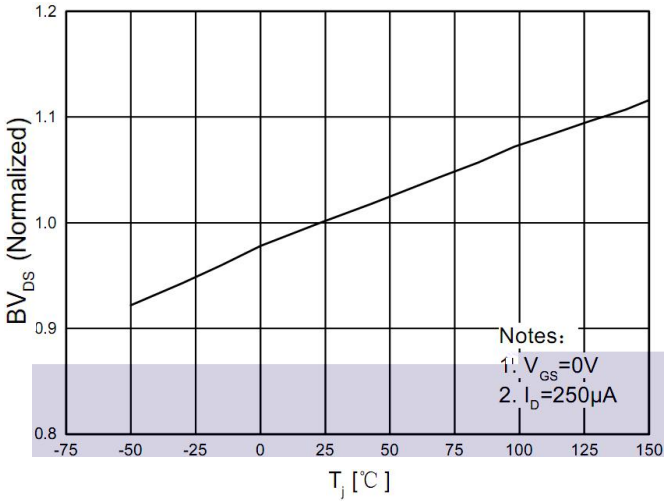
Capacitance Characteristics



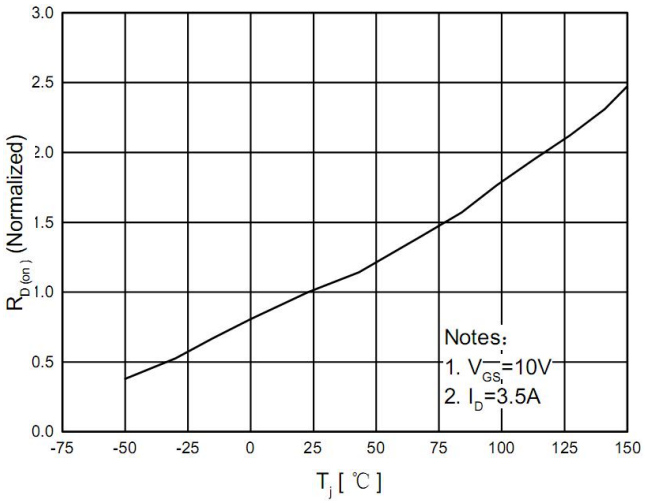
Gate Charge Characteristics



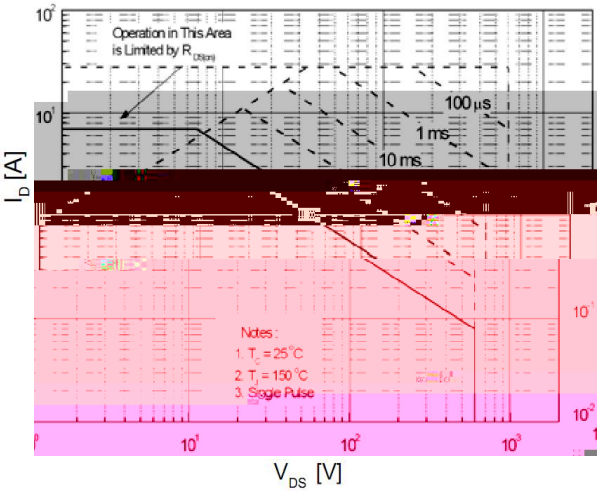
Breakdown Voltage Variation vs. Temperature



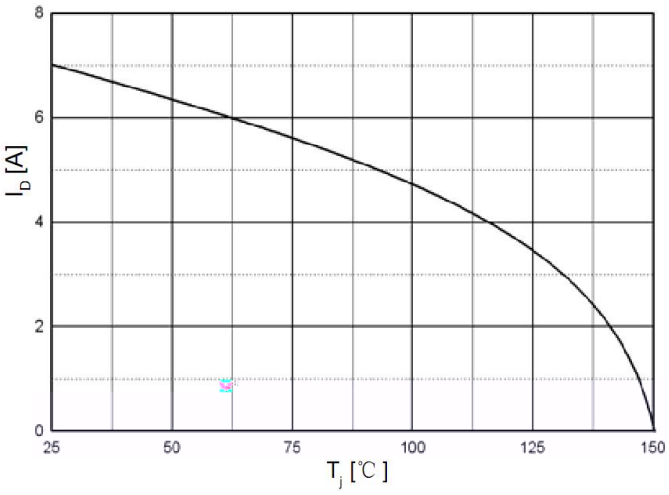
On-Resistance Variation vs. Temperature



Maximum Safe Operating Area



Maximum Drain Current Vs. Case Temperature



TO-220F Package Dimensions

UNIT：mm

SYMBOL	min	nom	max	SYMBOL	min	nom	max
A	9.80		10.60	D		2.54	
A1		7.00		D1	1.15		1.55
A2	2.90		3.40	D2	0.60		1.00
A3	9.10		9.90	D3	0.20		0.50
B1	15.40		16.40	E	2.24		2.84
B2	4.35		4.95	E1		0.70	
B3	6.00		7.40	E2		1.0 × 45 °	
C	3.00		3.70	E3	0.35		0.65
C1	15.00		17.00	E4	2.30		3.30
C2	8.80		10.80			30 °